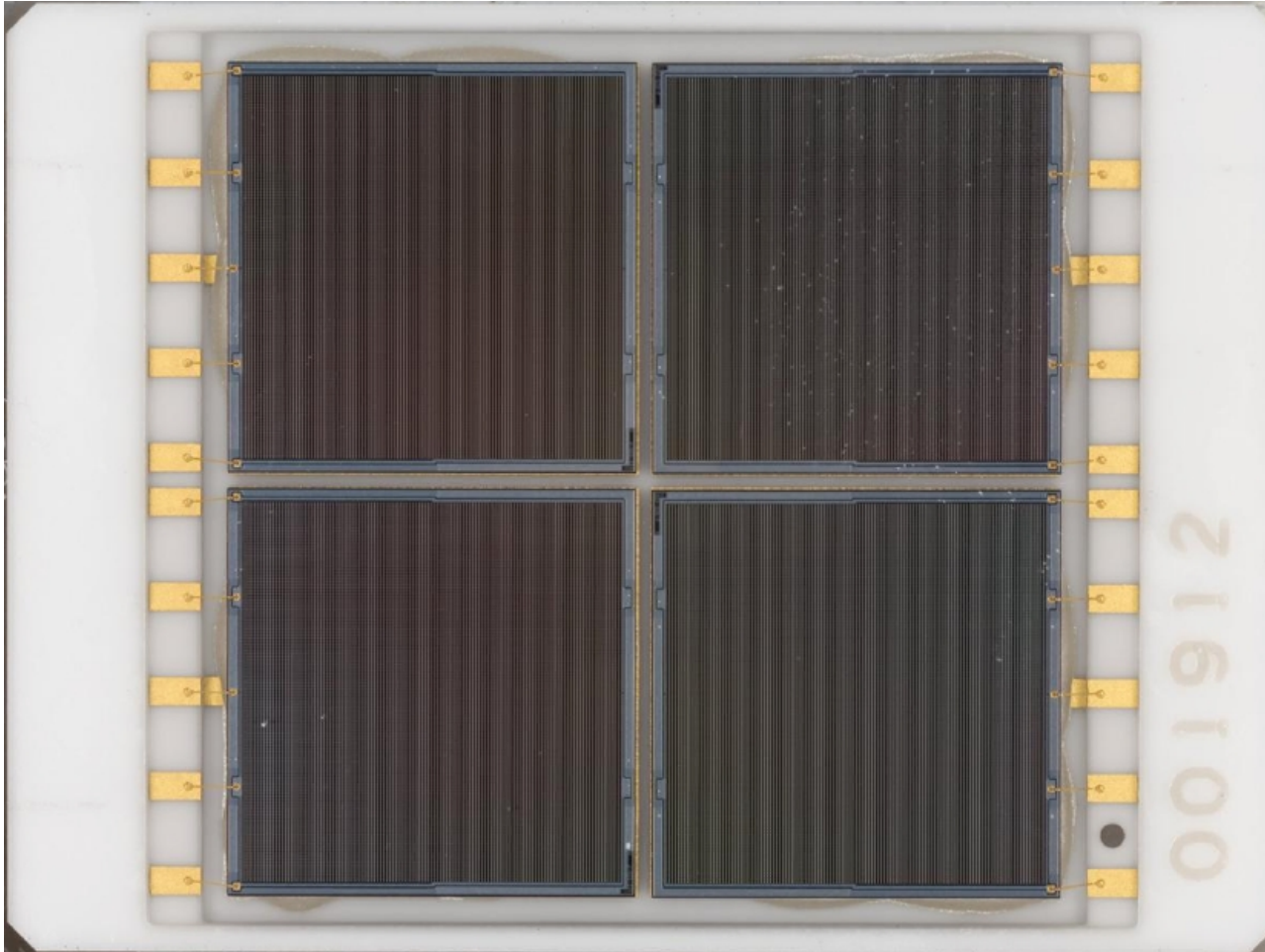


MPPC array measurement.
SiLab/UTFSM
26/09/2013

Outline

- Measurement stations.
- Measurement procedure.
- Results.

MPPC array

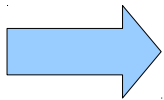
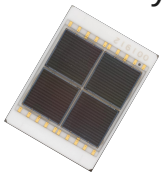


- Model: S12045(X)
- 2X2 array of 2x2 MPPC array.
16 individual MPPC cells 3x3 mm.
- Operational voltage around 70 V.
- 3600 pixel 50x50 um per MPPC.

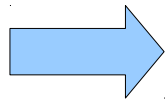
Measurement program

We used three stations to get the complete characterization of the MPPC arrays

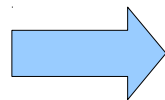
Uncharacterized
MPPC array



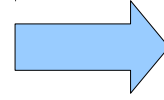
Visual
inspection.
Station 1



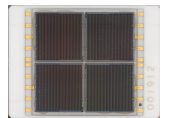
PDE at room
temperature.
Station 2



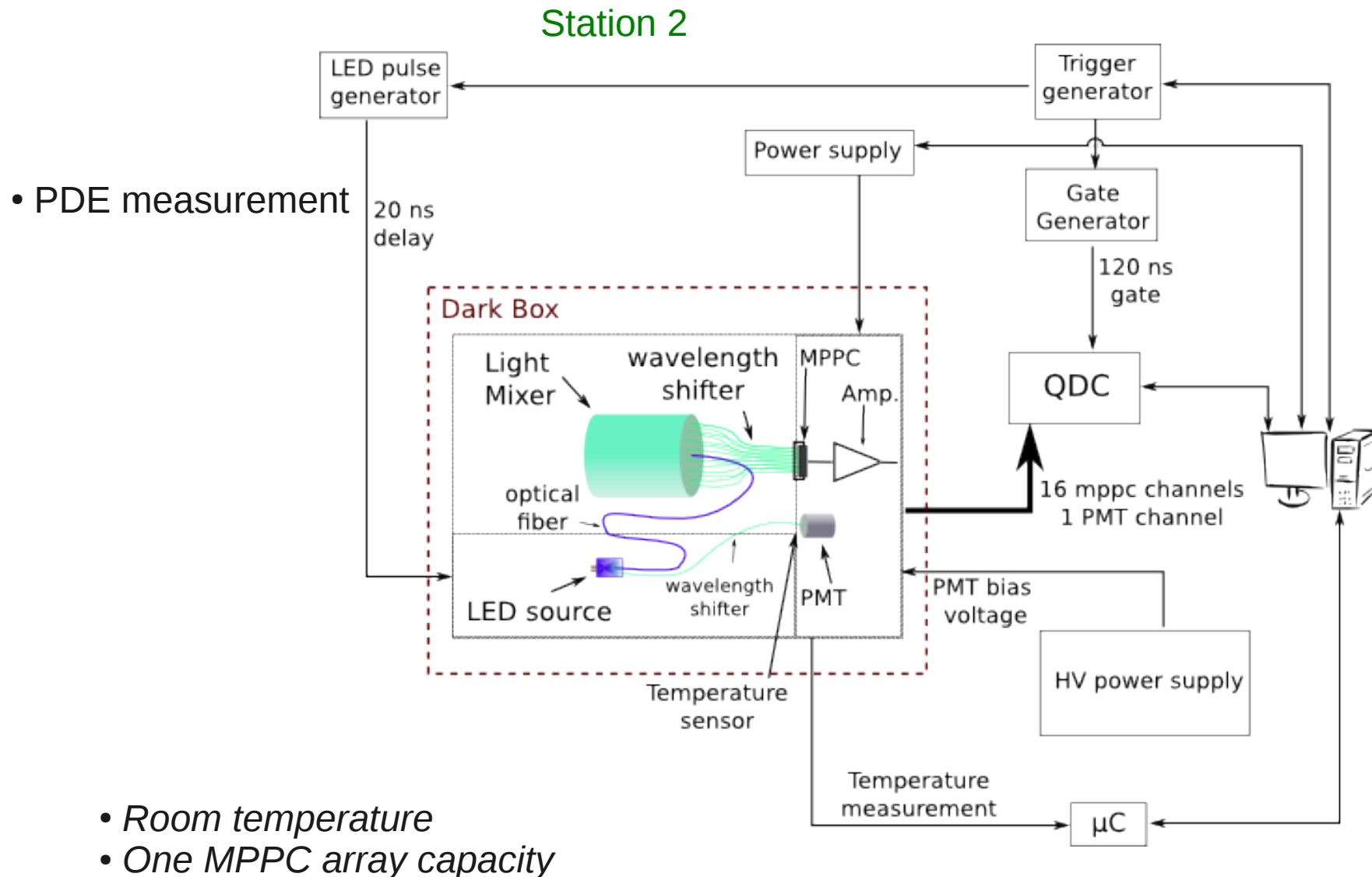
Breakdown voltage,
Gain, optical crosstalk,
dark rate at 5C, 7C, 20C
Station 3



Characterized
MPPC array



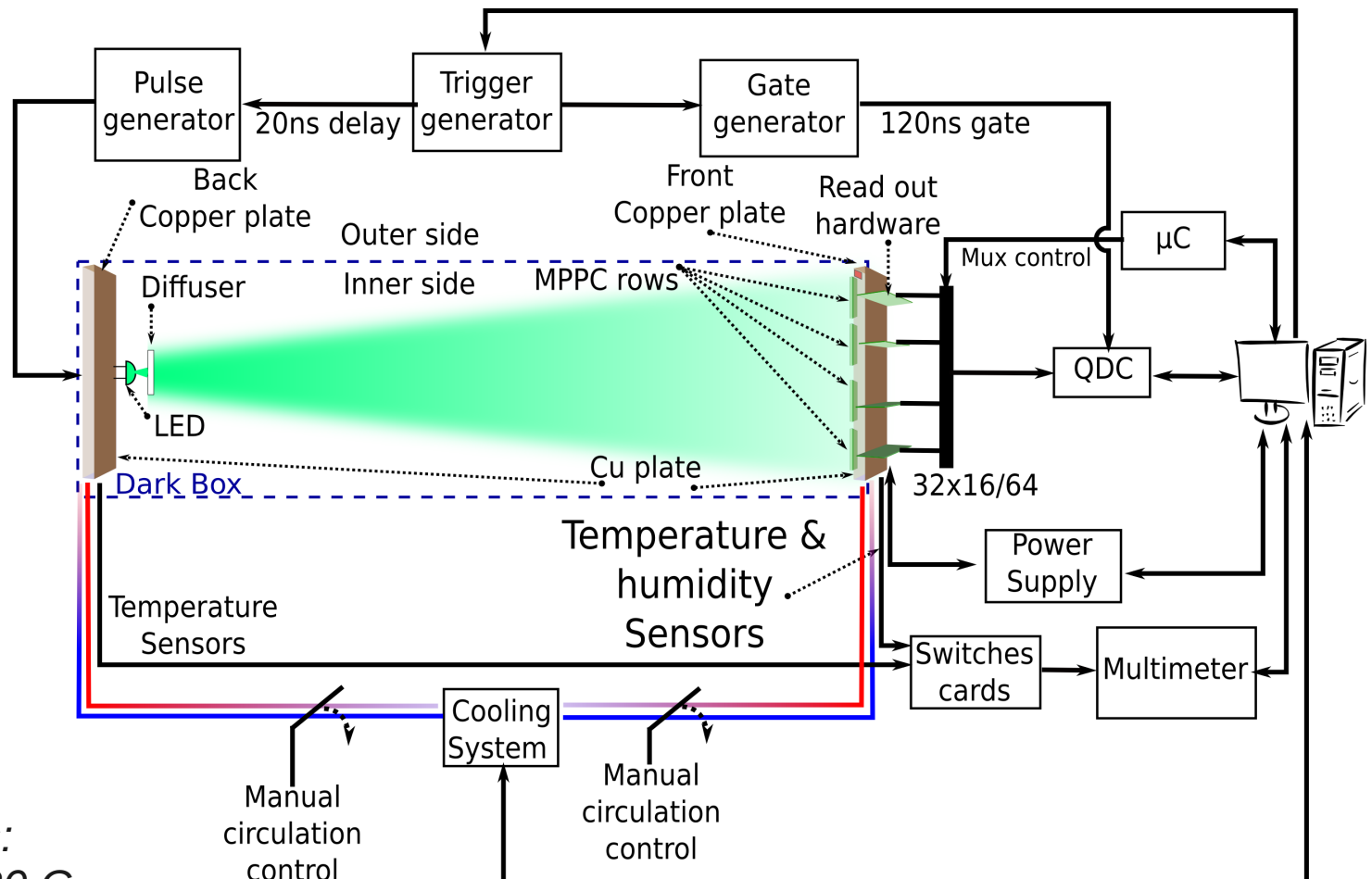
Measurement stations (1)



Measurement stations (2)

Station 3

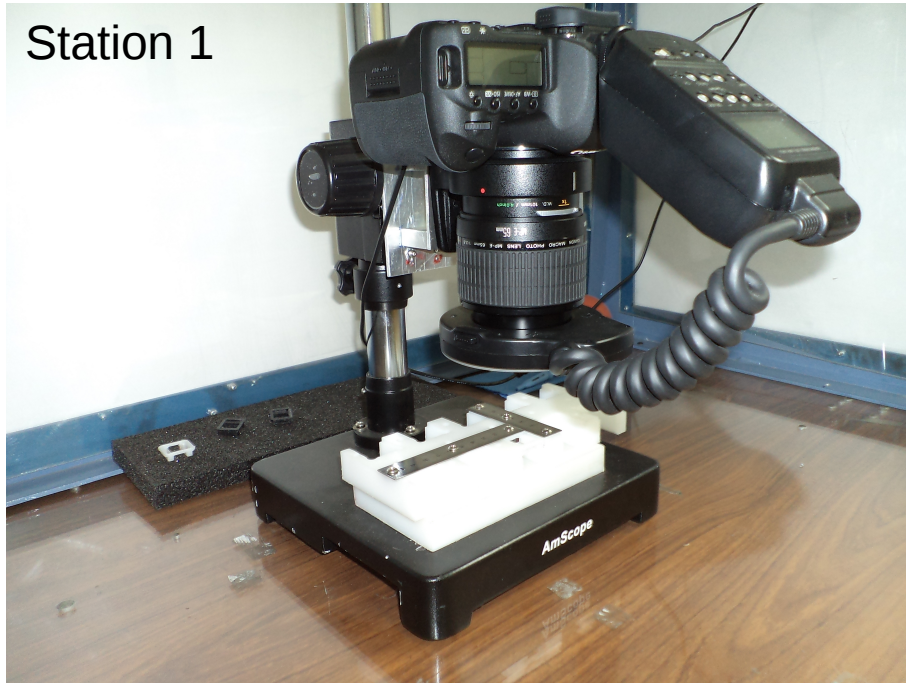
- Breakdown voltage
- Gain
- Optical crosstalk
- Dark rate



- *Temperatures:*
5 C, 7 C and 20 C
- *32 MPPC array capacity*

Measurement stations (3)

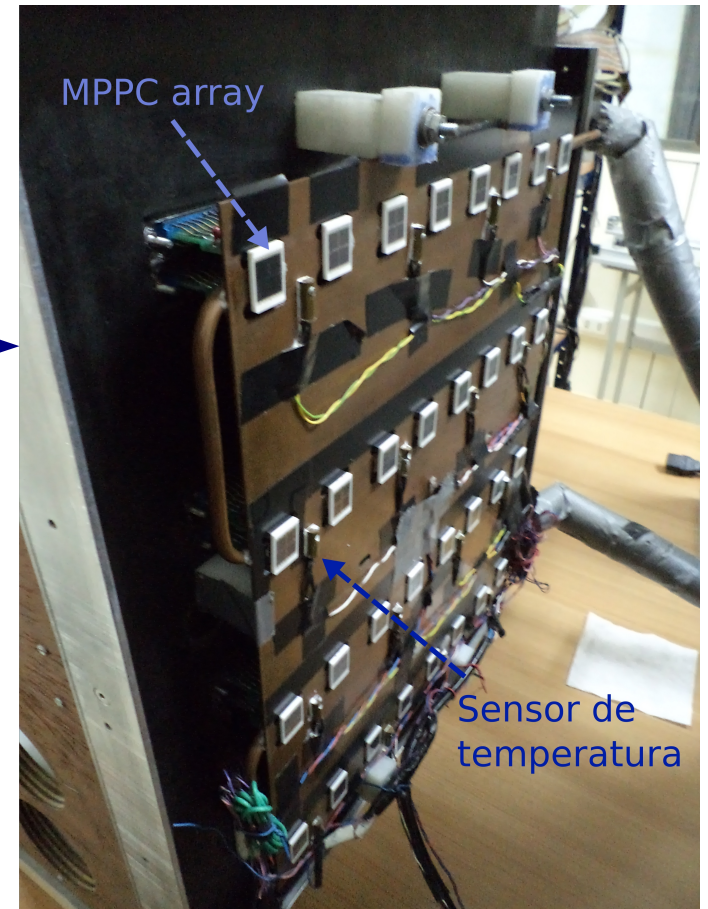
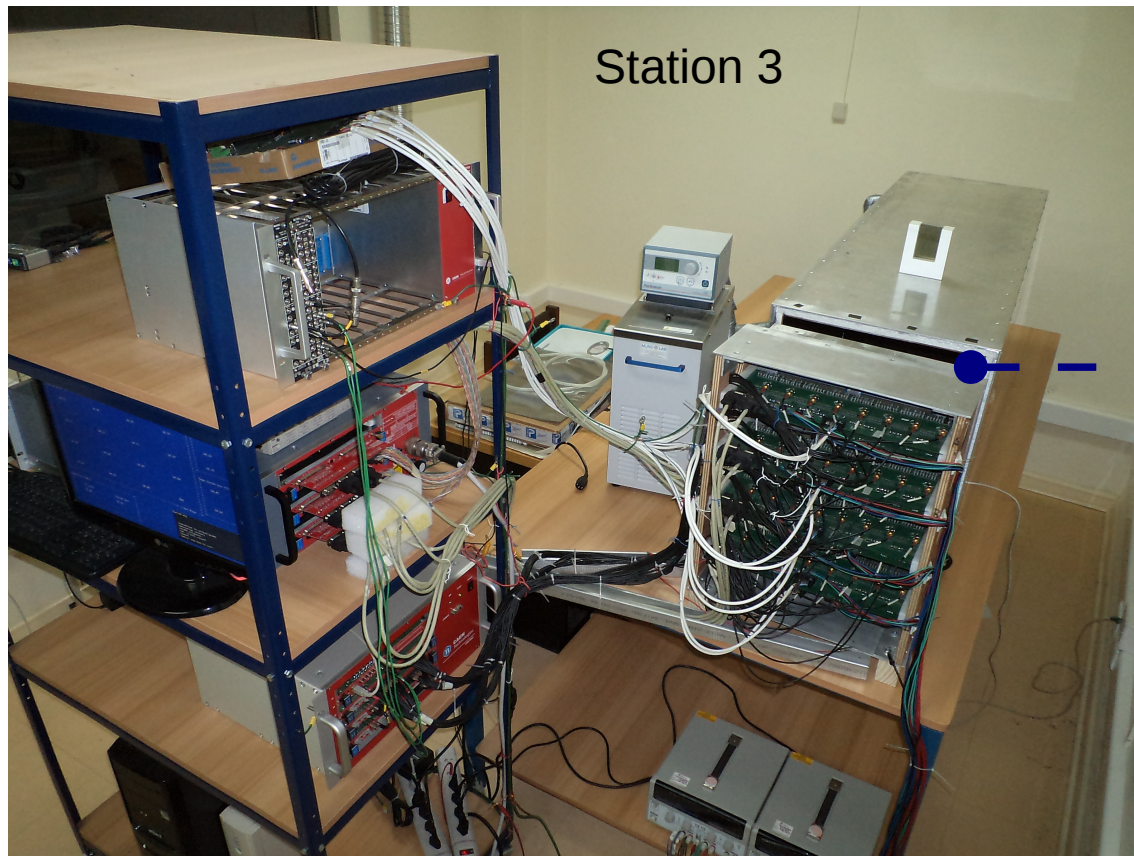
Station 1



Station 2



Measurement stations (4)

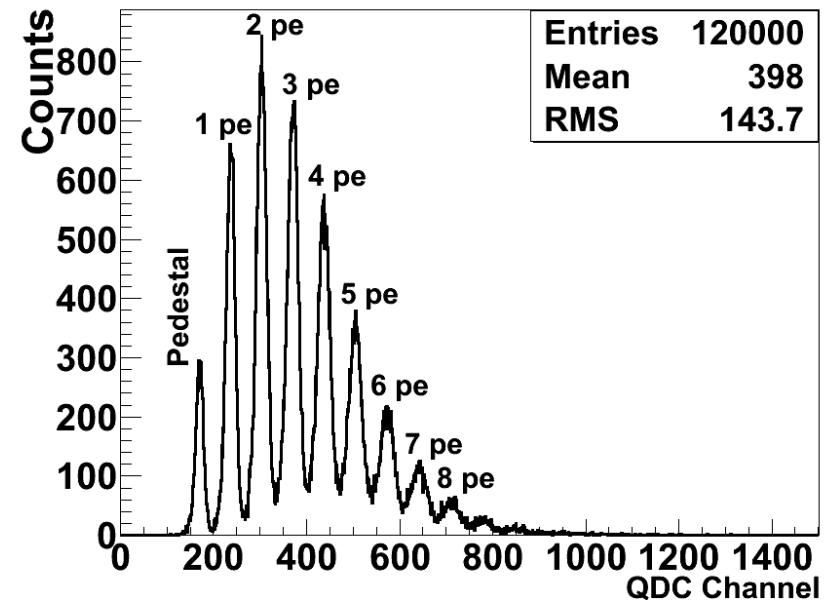
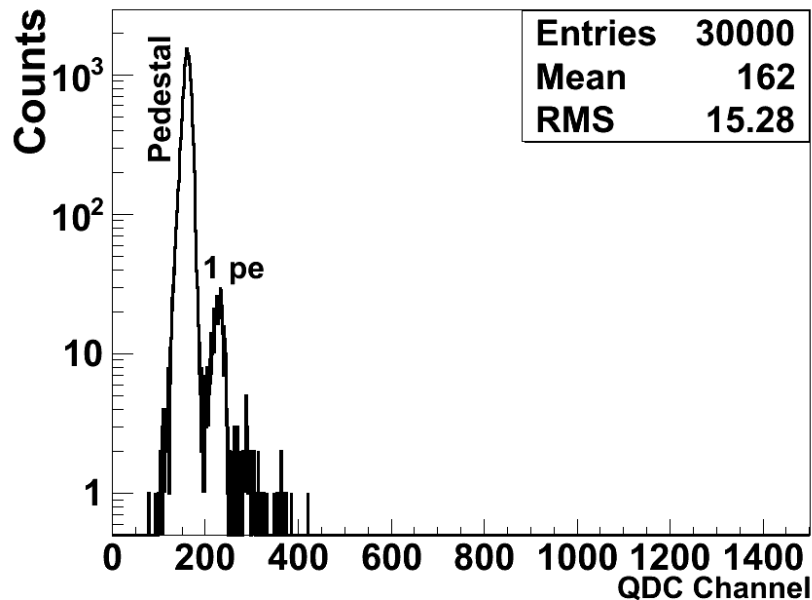


Outline

- Measurement stations.
- **Measurement procedure.**
- Results.

Measurement procedure

Given a temperature T_{USM} , for each cell in one MPPC array we have histograms with and without light at 13 different bias voltages¹ V_i , starting with corrected Hamamatsu operational voltage², decreasing -0,1 V steps.

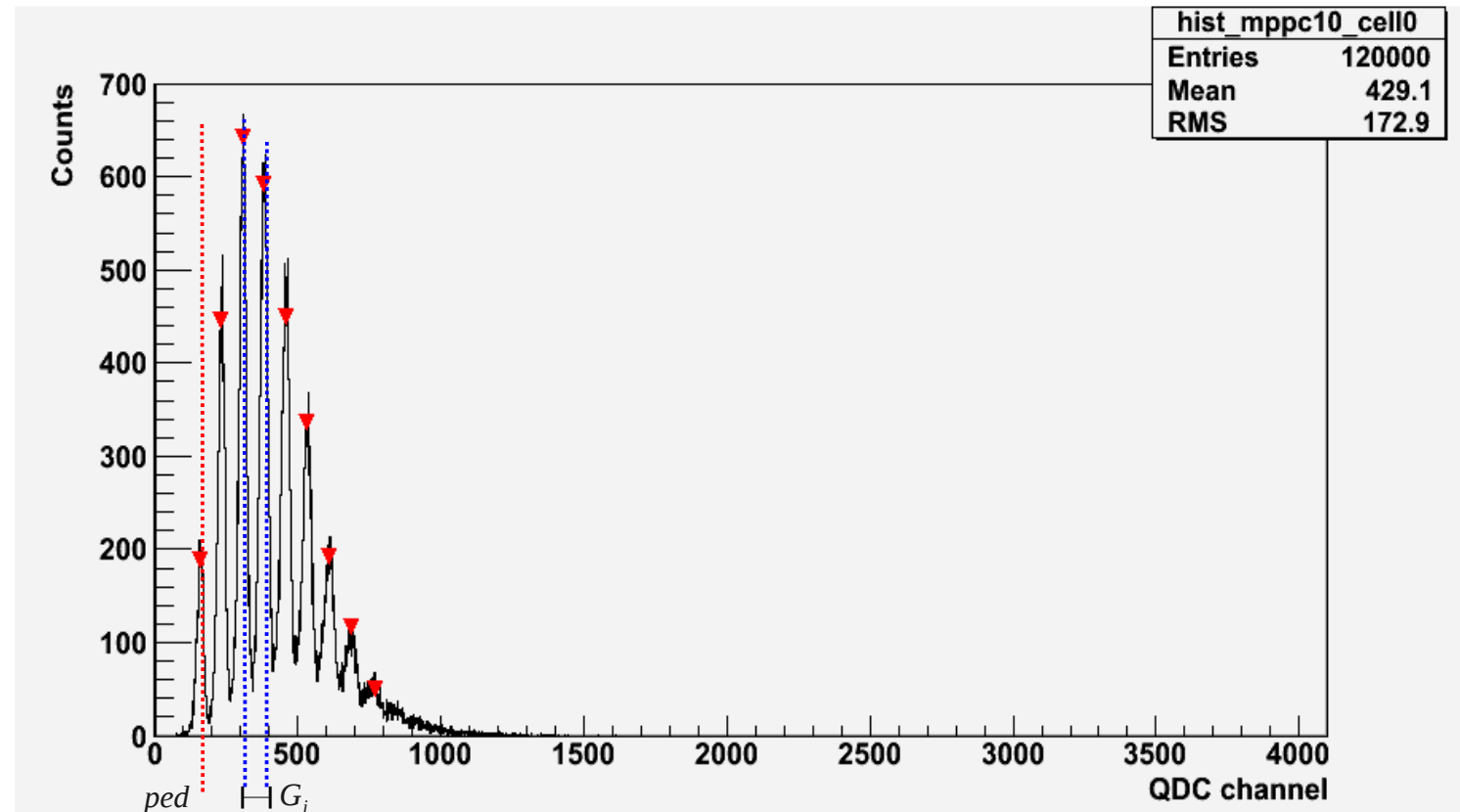


¹ $V_i = V_0 - 0,1 \cdot i$

² temperature correction:

$$\Delta t \cdot 0.056 [V] \Rightarrow V_0 = \bar{V}_{hamamatsu} + (25 - T_{usm}) \cdot 0.056$$

From these histograms we get gain (G_i), average number of photoelectrons ($\langle N \rangle$), Optical cross-talk (OC) according to:



Mean

RMS

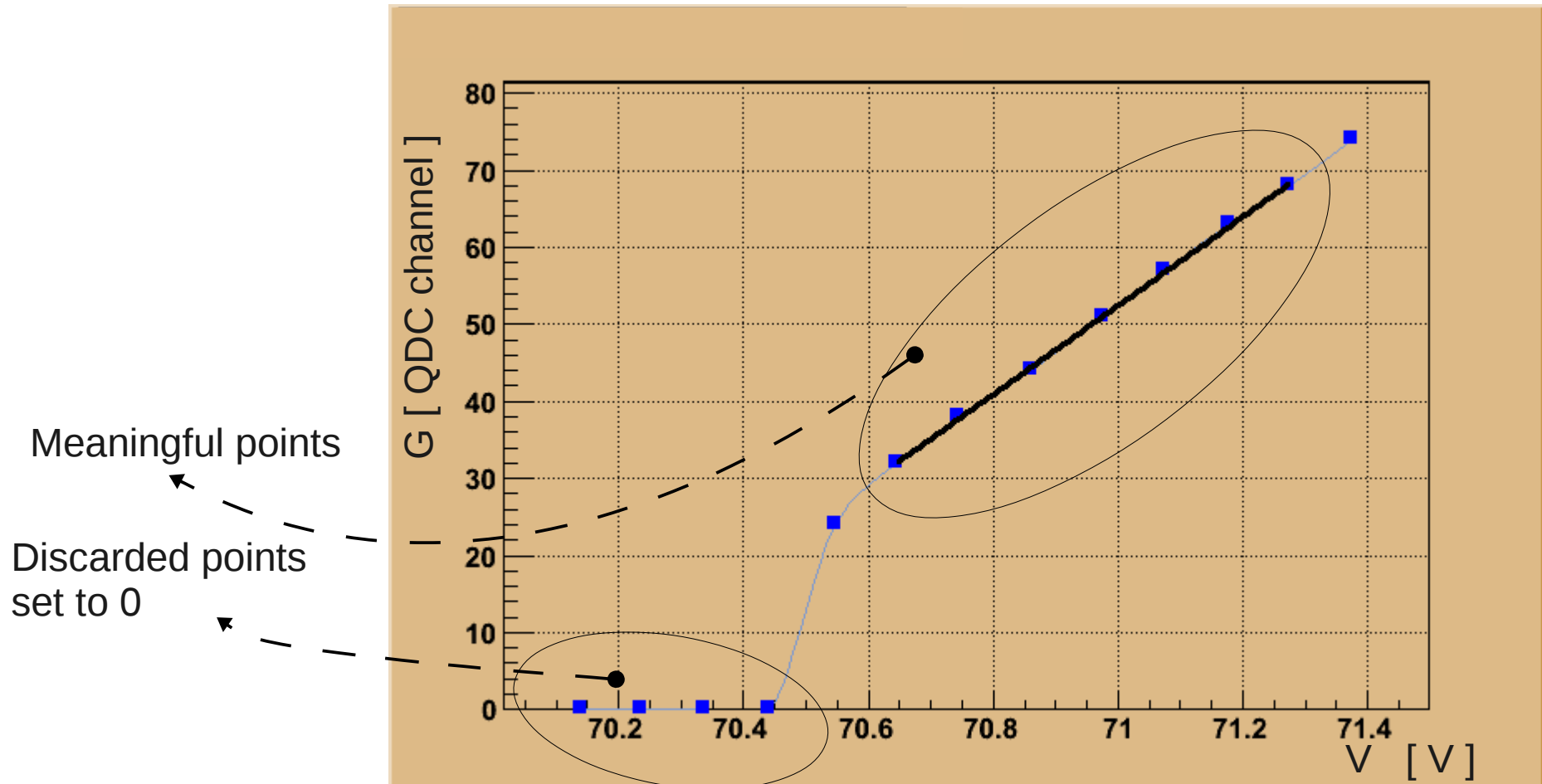
ped

G_i

$$OC = \frac{\sigma^2 - \mu + \sqrt{(\sigma^2 - \mu)^2 + 4\mu^2}}{2\mu} - 1 \quad (1)$$

$$\langle N \rangle = \frac{-(\sigma^2 - \mu) + \sqrt{(\sigma^2 - \mu)^2 + 4\mu^2}}{2} \quad (2)$$

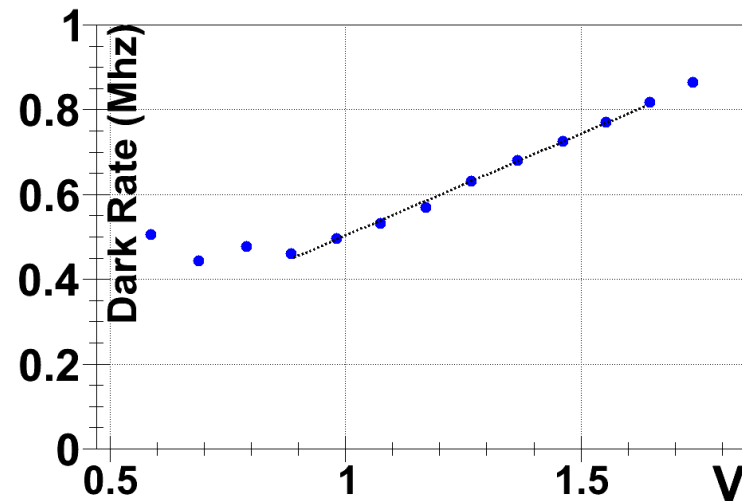
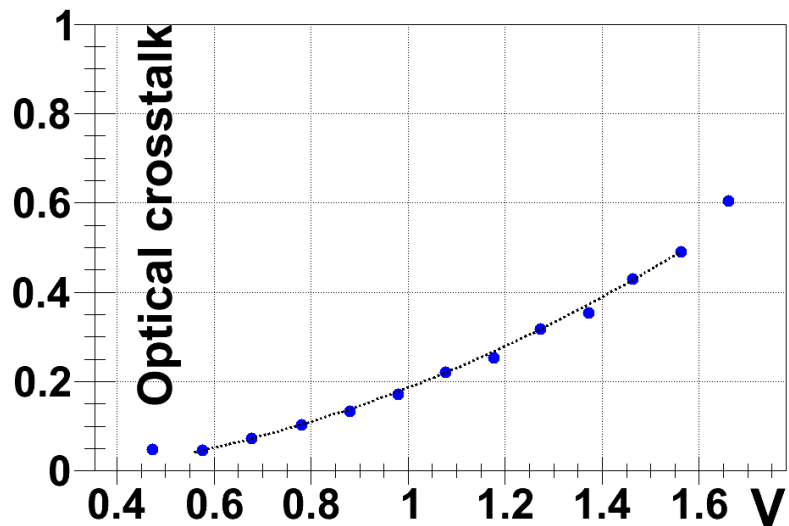
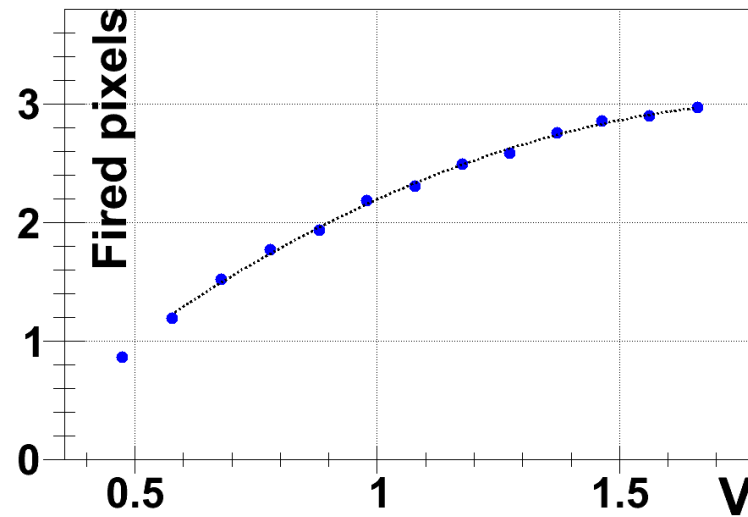
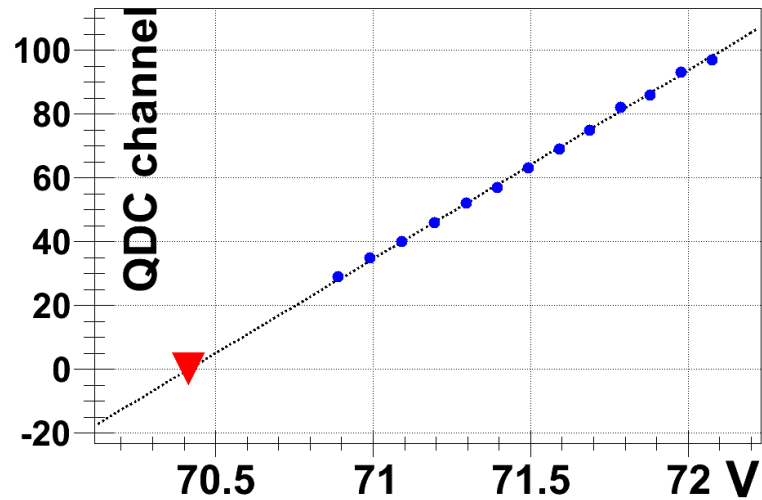
For each channel we estimate Break Down Voltage from first order polynomial fit over the meaningful voltages.



$$G(V) = p_0 + p_1 \cdot V$$

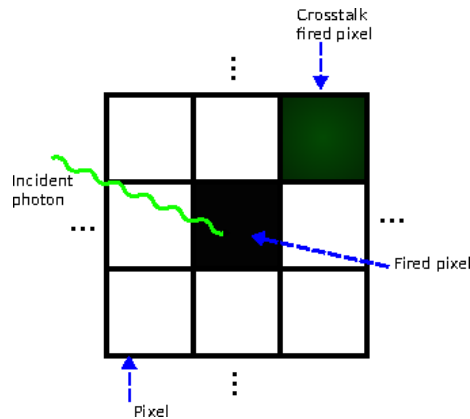
$$G(V_{BDV}) = 0 \Rightarrow V_{BDV} = -p_0/p_1$$

Results for one MPPC channel



Optical crosstalk extraction

- We start with a probabilistic model.
- We write expressions for mean and variance of this model.
- Using the mean and variance we extract the mean number of photoelectrons and the optical crosstalk.



$$P_{xt}(k|1) = \binom{N_n}{k} p_{xt}^k (1 - p_{xt})^{N_n - k}$$

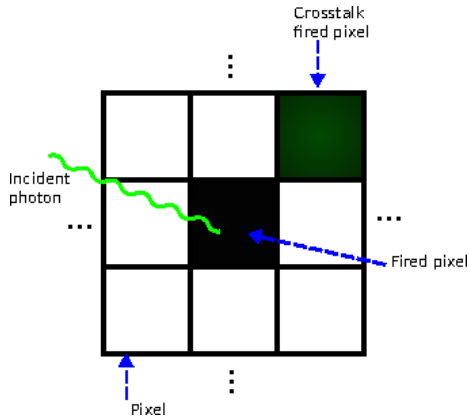
$$\begin{aligned} P_{xt}(k = k_1 + \dots + k_i | i) &= \sum_{j=1}^i \binom{N_n}{k_i} p_{xt}^{k_i} (1 - p_{xt})^{N_n - k_i} \\ &= \binom{N_n i}{k} p_{xt}^k (1 - p_{xt})^{N_n i - k} \end{aligned}$$

$$P_{xt}(k|i) = \frac{(iOC)^k e^{-(iOC)}}{k!}$$

$$P(n) = \sum_{k=0}^n \frac{\langle N \rangle^k e^{-\langle N \rangle}}{k!} \times \frac{(k \times OC)^{n-k} e^{-k \times OC}}{(n-k)!}$$

Optical crosstalk extraction

- We start with a probabilistic model.
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$$P(n) = \sum_{k=0}^n \frac{\langle N \rangle^k e^{-\langle N \rangle}}{k!} \times \frac{(k \times OC)^{n-k} e^{-k \times OC}}{(n-k)!}$$

$$\mu = G'(1)$$

$$G(z) = E[Z^X] = \sum_{j=0}^{\infty} p_j z^j$$

$$\sigma^2 = G''(1) - G'(1)^2 + G'(1)$$

$$\mu = \langle N \rangle (1 + OC)$$

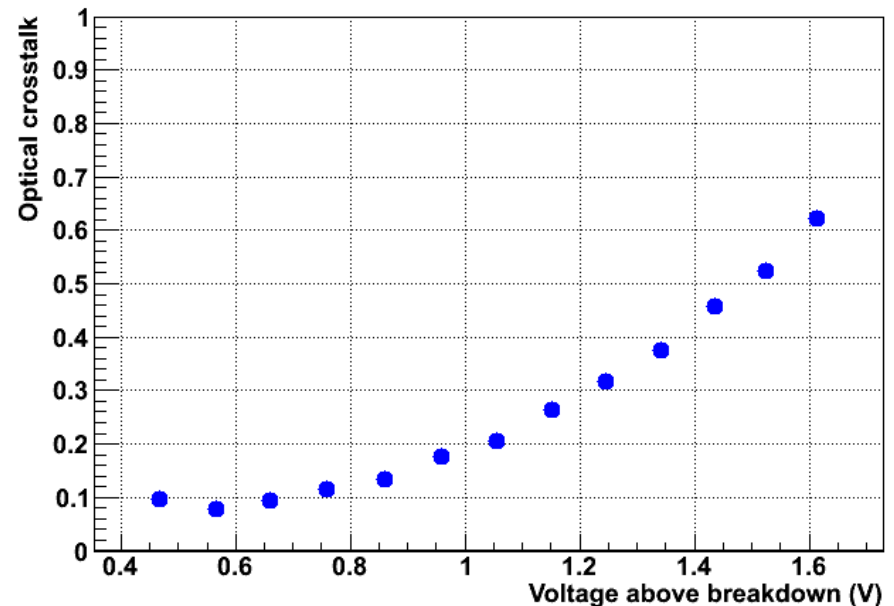
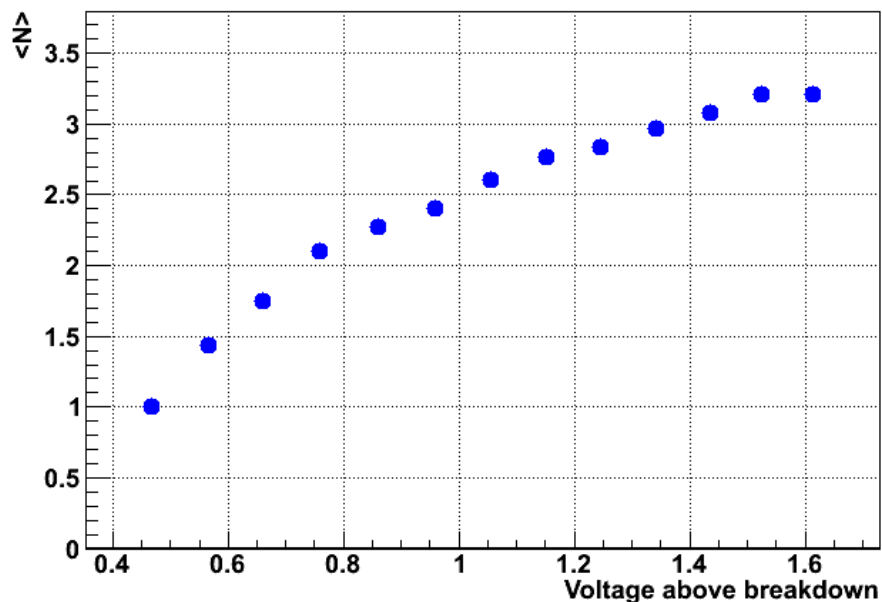
$$\sigma^2 = \langle N \rangle (1 + 3OC + OC^2)$$

$$OC = \frac{\sigma^2 - \mu + \sqrt{(\sigma^2 - \mu)^2 + 4\mu^2}}{2\mu} - 1 \quad (1)$$

$$\langle N \rangle = \frac{-(\sigma^2 - \mu) + \sqrt{(\sigma^2 - \mu)^2 + 4\mu^2}}{2} \quad (2)$$

Optical crosstalk extraction

- We start with a probabilistic model.
- We write expressions for mean and variance of this model.
- Using the mean and variance we extract the mean number of photoelectrons and the optical crosstalk.



PDE extraction (station 3)

- Calibration using 400 MPPC array.
- Using some MPPC array with known PDE from station 2, we estimate the PDE in station 3.

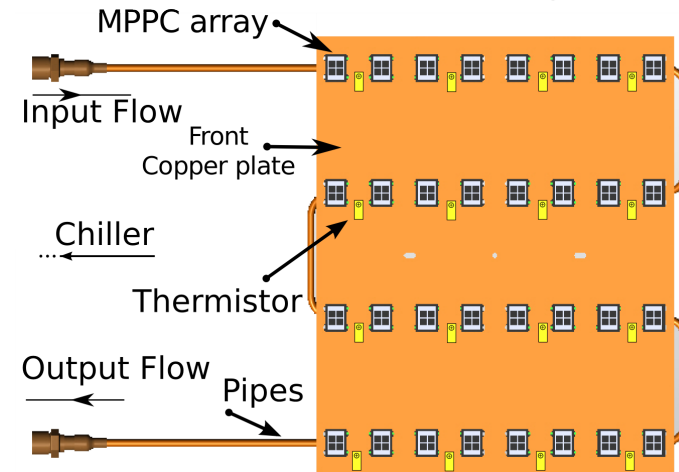
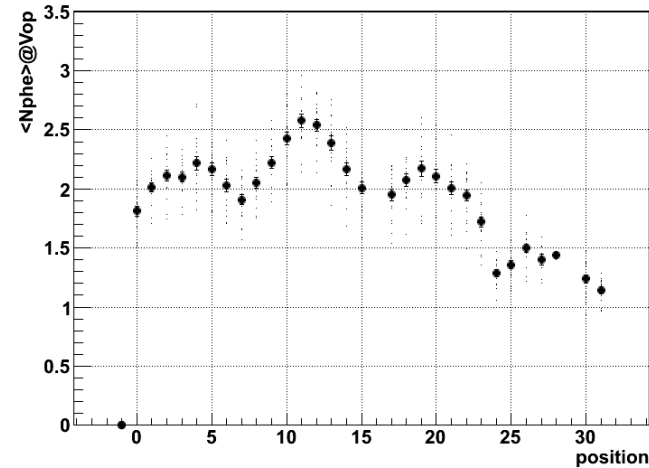
$$n_{phe}(pos) = PDE(pos) \times LUT_T(pos) \times C$$

$$A_{phe}(pos) = LUT_T(pos) \times C$$

$$\hat{C} = \frac{1}{|P|} \sum_{pos \in P} \frac{n_{phe}(pos)}{LUT_T(pos) \times PDE(pos)}$$

$$\hat{A}_{phe}(pos) = LUT_T(pos) \times \hat{C}$$

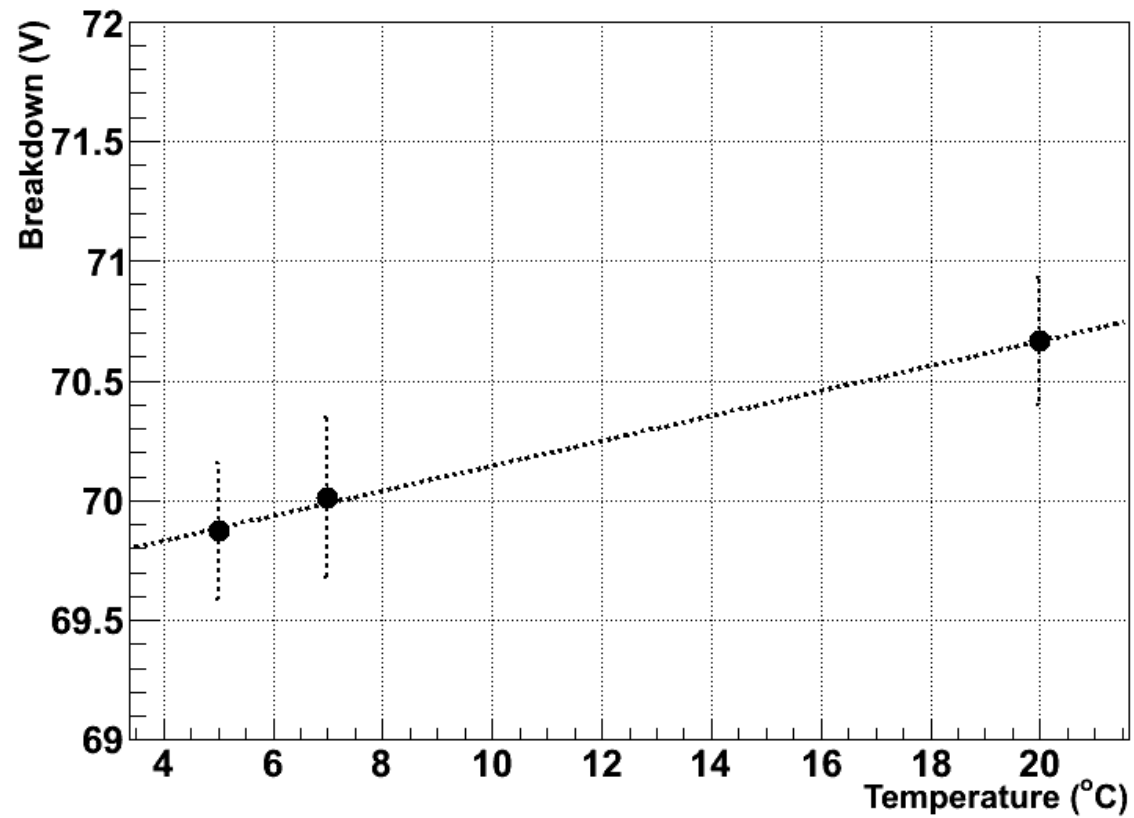
$$PDE(pos) = \frac{n_{phe}(pos)}{\hat{A}_{phe}(pos)}$$



Outline

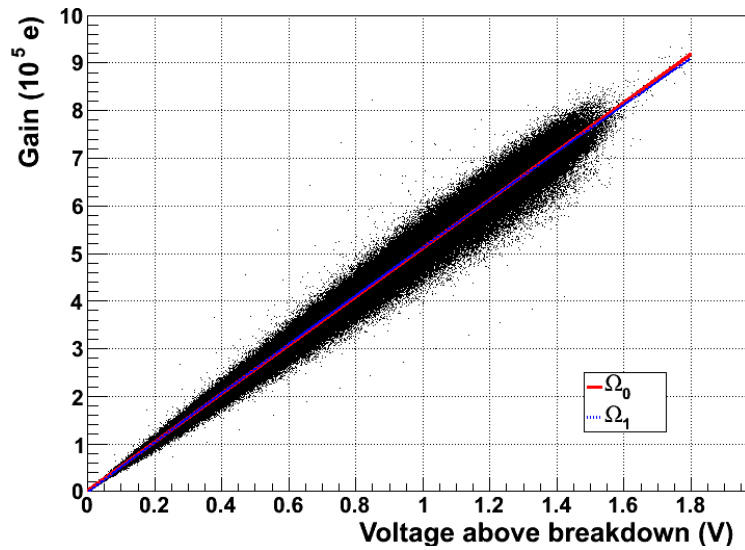
- Measurement stations.
- Measurement procedure.
- **Results.**

Breakdown voltage

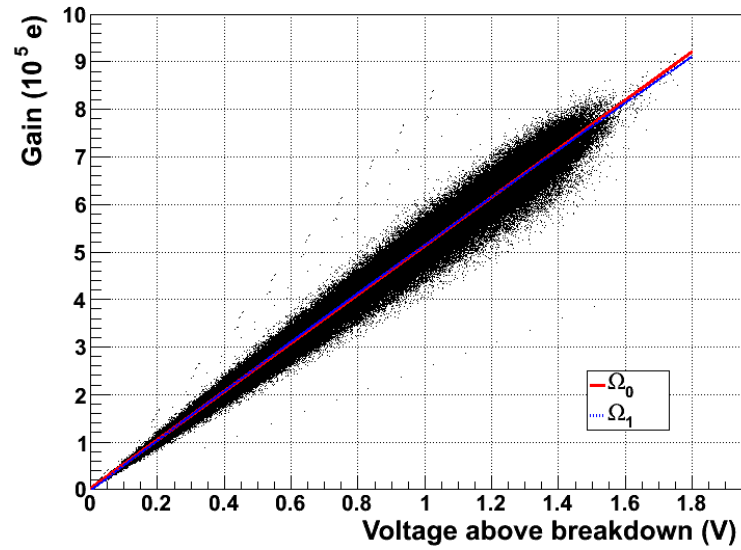


Gain

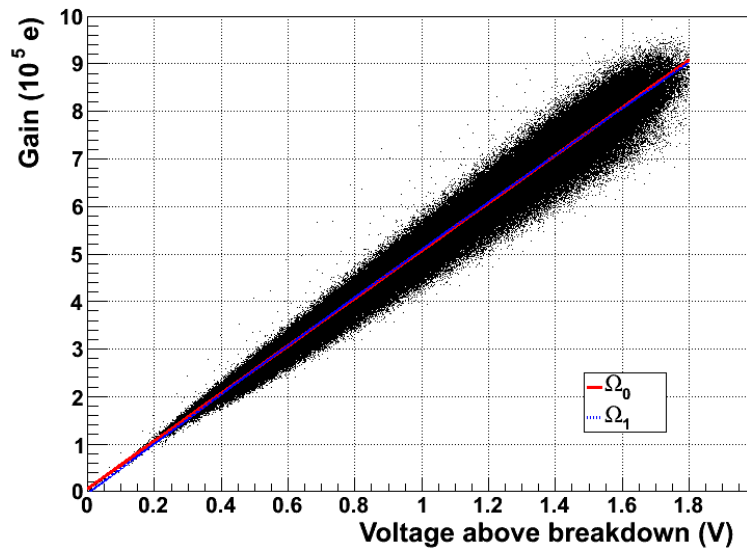
5C



7C



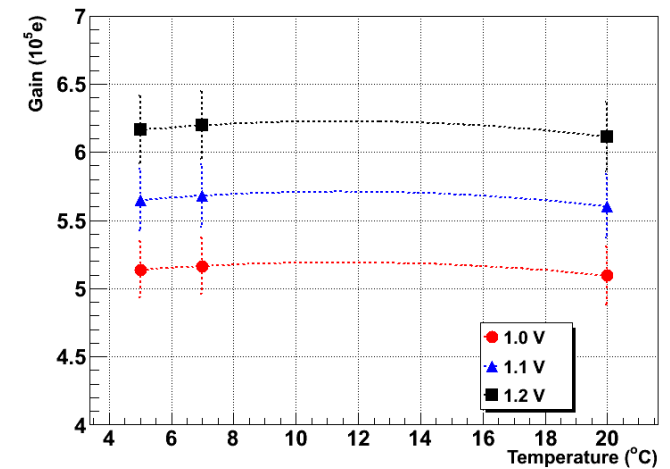
20C



$$G_5 = 5.09 \Delta V$$

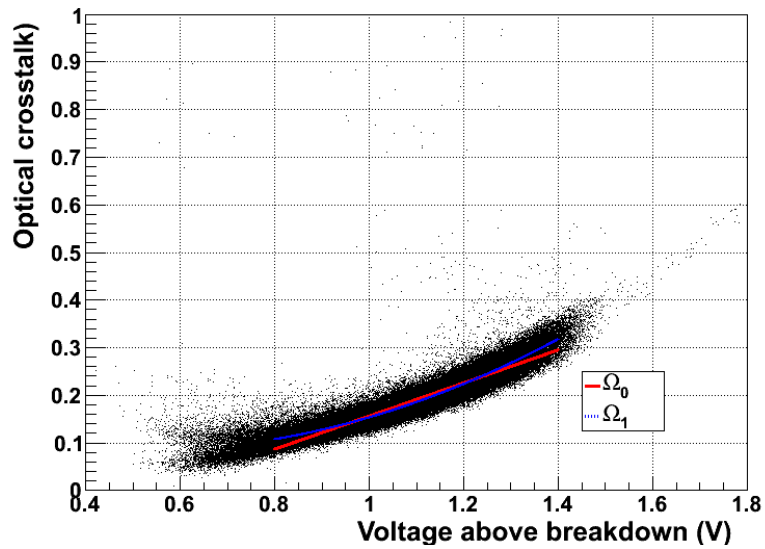
$$G_7 = 5.11 \Delta V$$

$$G_{20} = 5.01 \Delta V$$

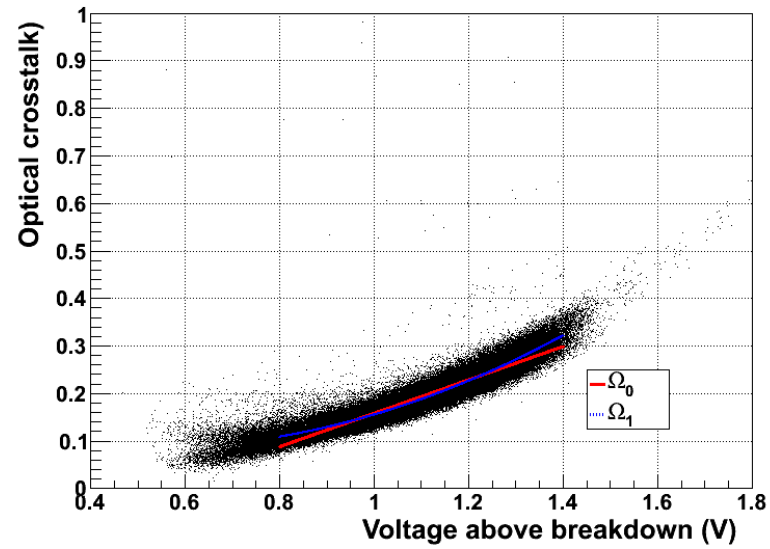


Crosstalk

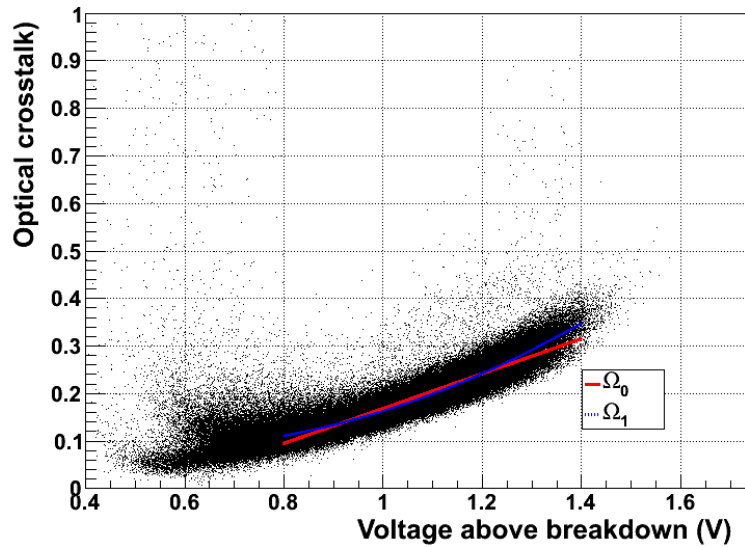
5C



7C



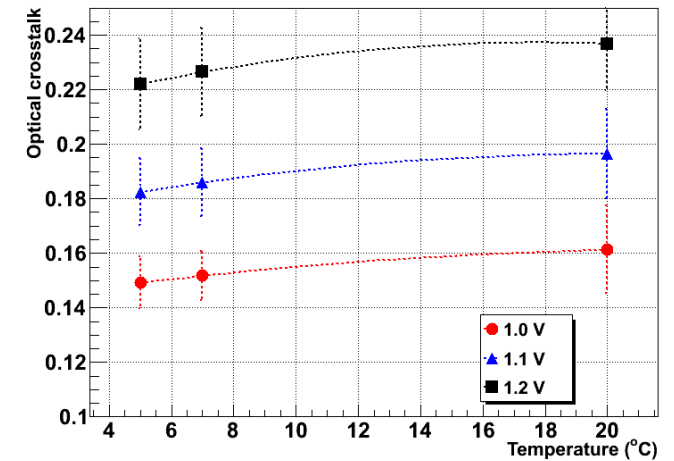
20C



$$XT_5 = 0.302\Delta V^2 - 0.312\Delta V + 0.164$$

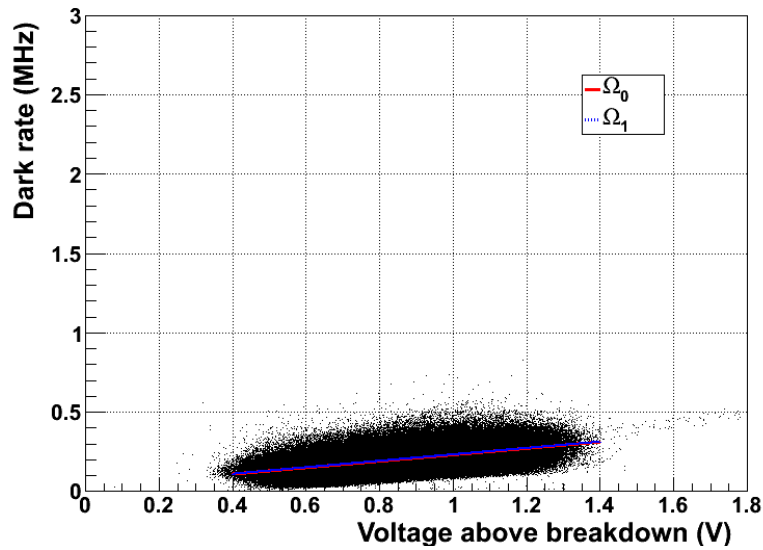
$$XT_7 = 0.307\Delta V^2 - 0.319\Delta V + 0.167$$

$$XT_{20} = 0.338\Delta V^2 - 0.347\Delta V + 0.172$$

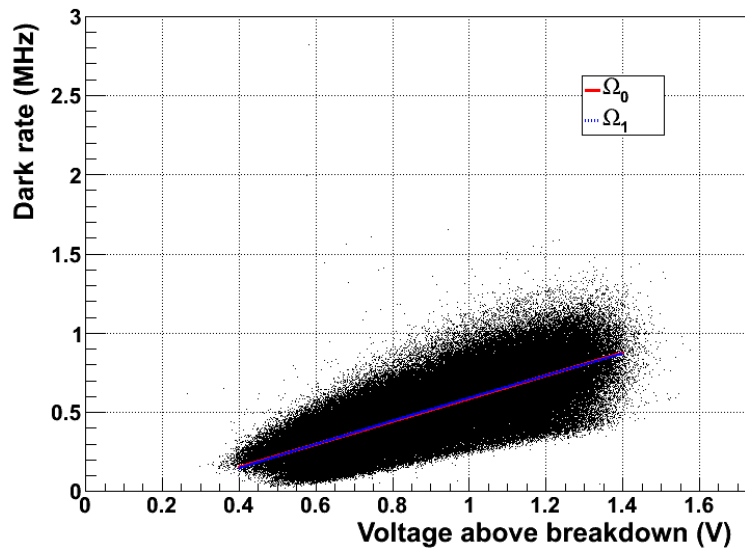
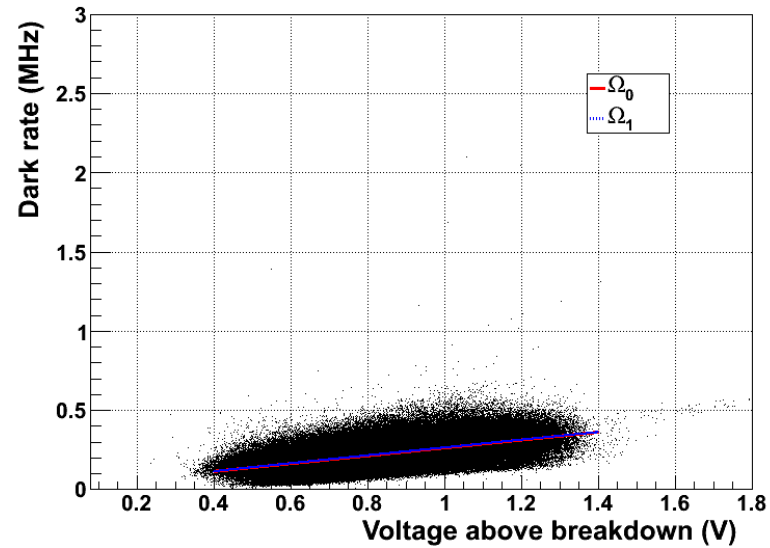


Dark rate

5C



7C

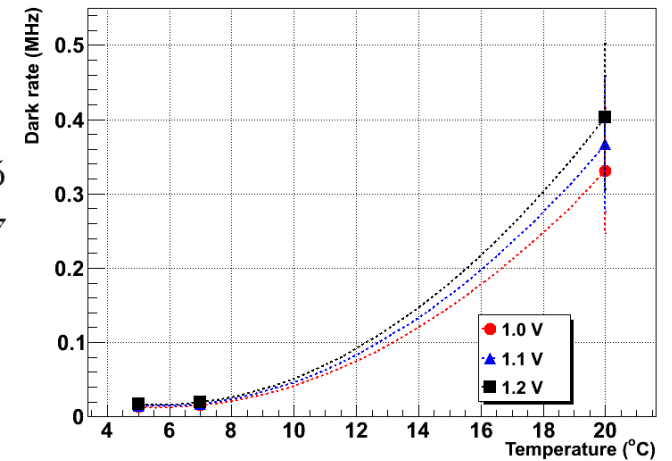


20C

$$DR_5 = 0.203\Delta V + 0.0285$$

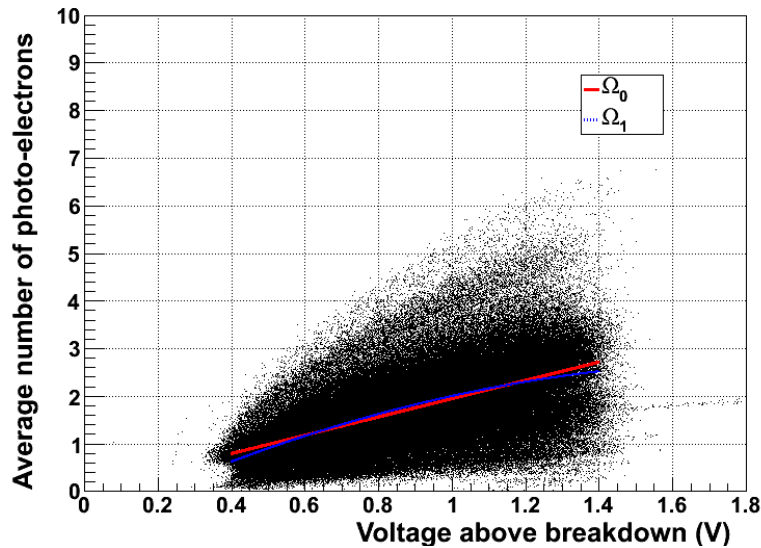
$$DR_7 = 0.248\Delta V + 0.0157$$

$$DR_{20} = 0.723\Delta V - 0.135$$

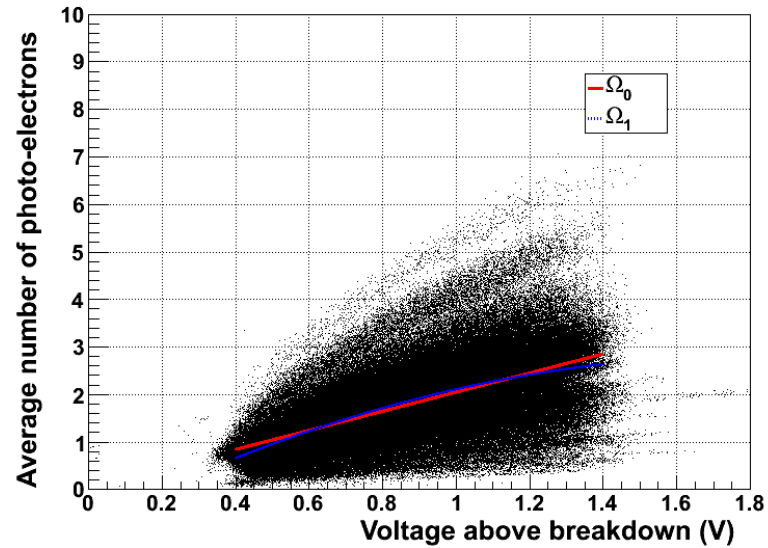


Mean number of photoelectrons

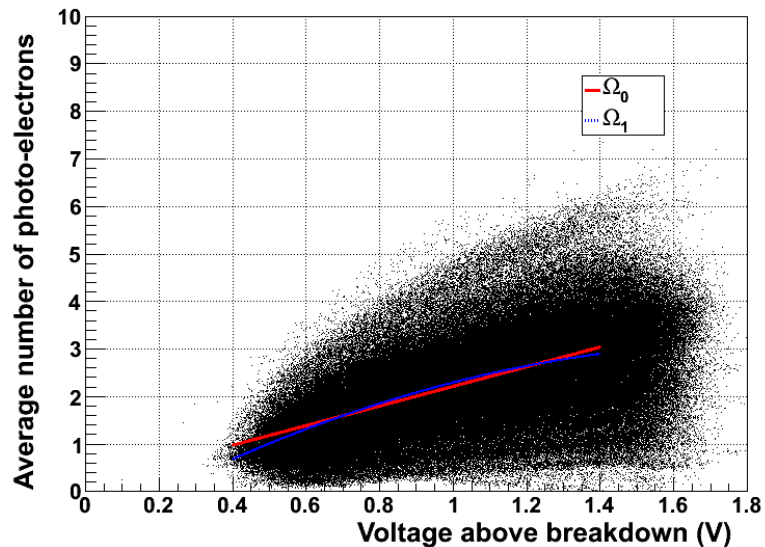
5C



7C



20C

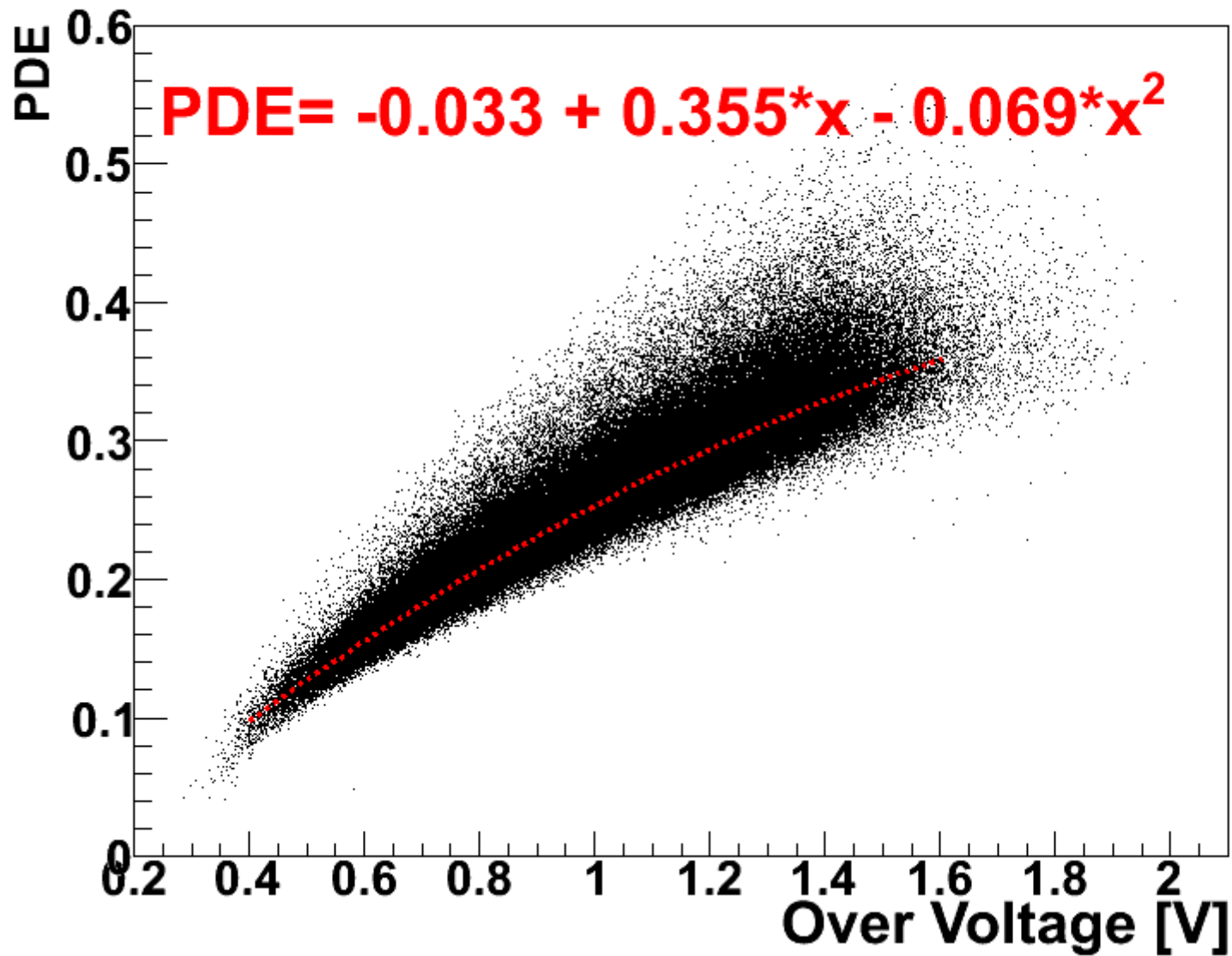


$$\langle N \rangle_5 = -1.00\Delta V^2 + 3.69\Delta V - 0.69$$

$$\langle N \rangle_7 = -1.09\Delta V^2 + 3.95\Delta V - 0.75$$

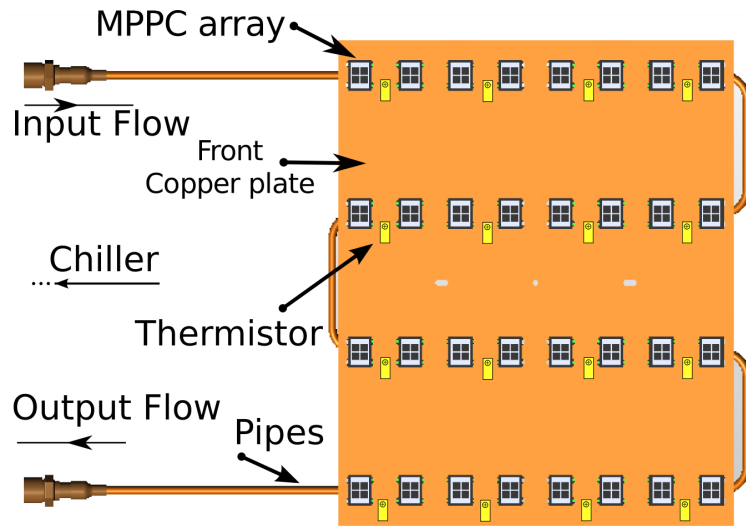
$$\langle N \rangle_{20} = -1.18\Delta V^2 + 4.34\Delta V - 0.87$$

PDE

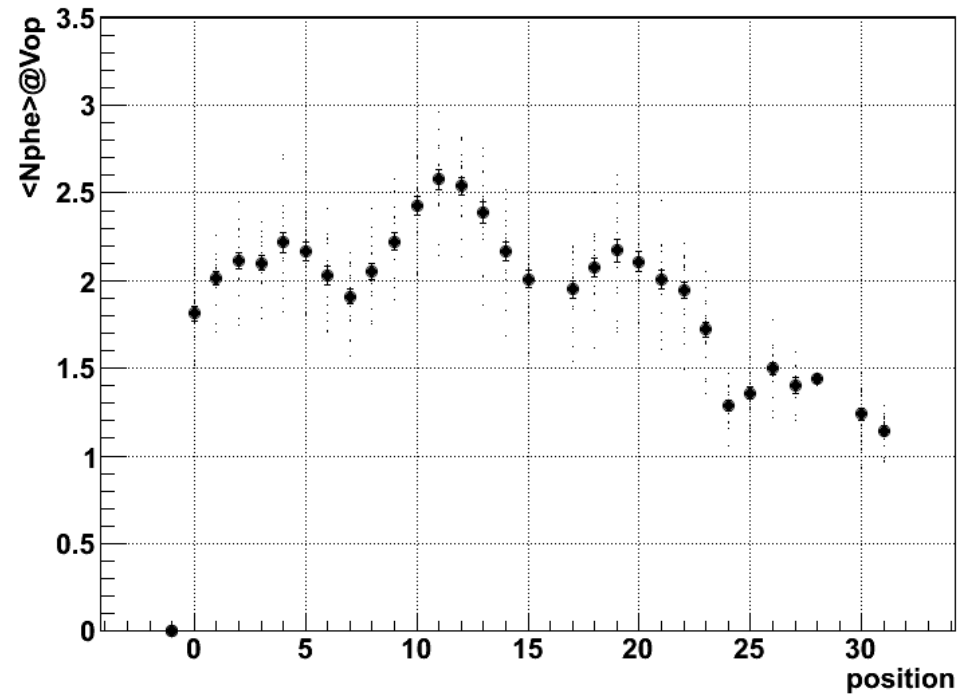


BACKUP SLIDES

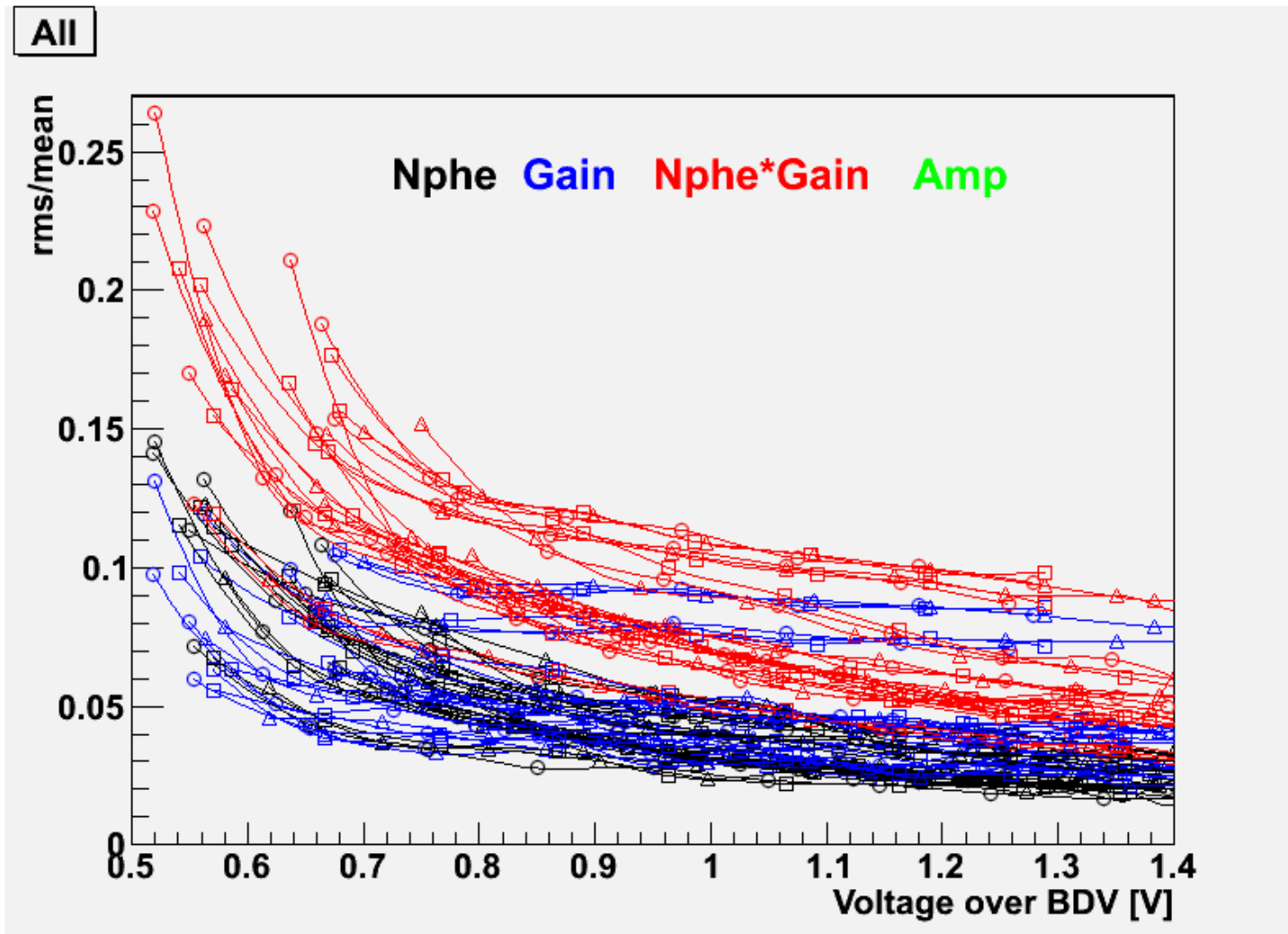
Light distribution across Cu plate



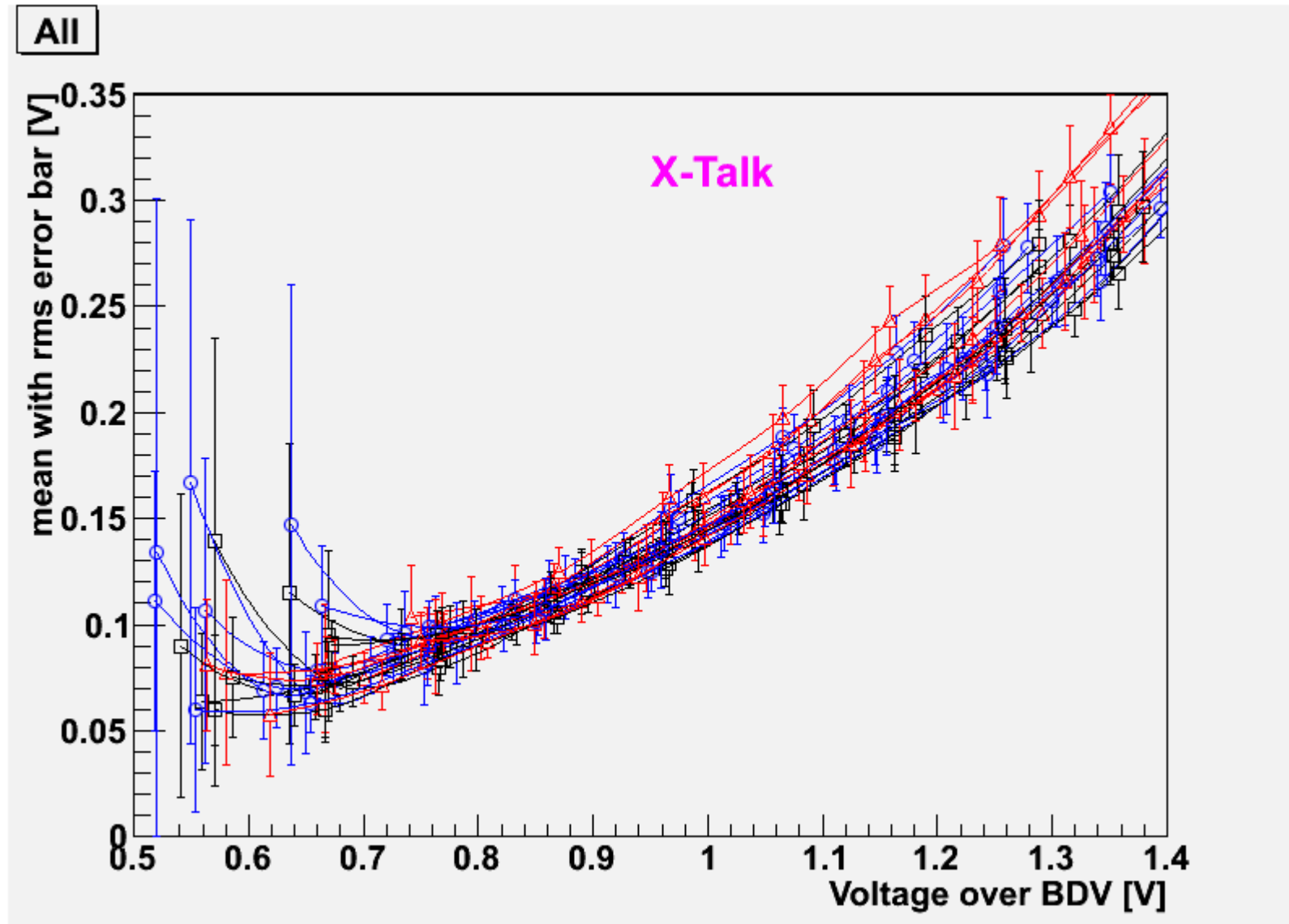
: MPPC position
 # : Sensor position



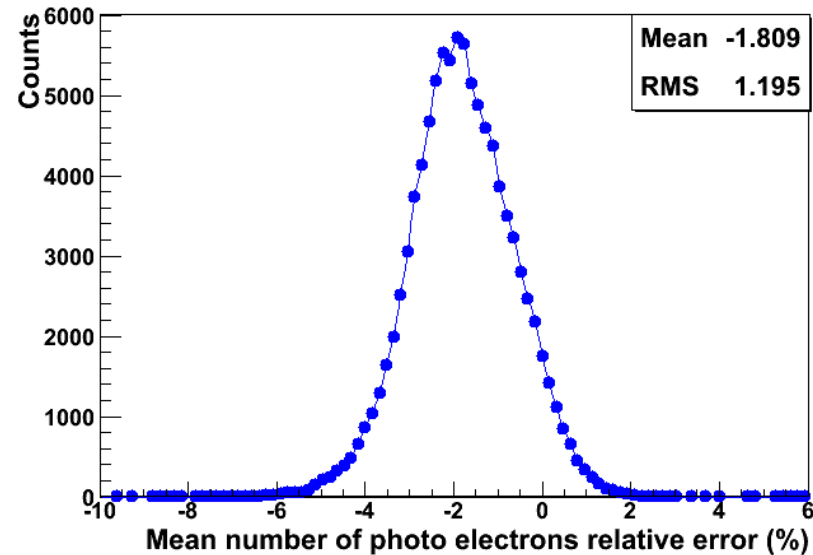
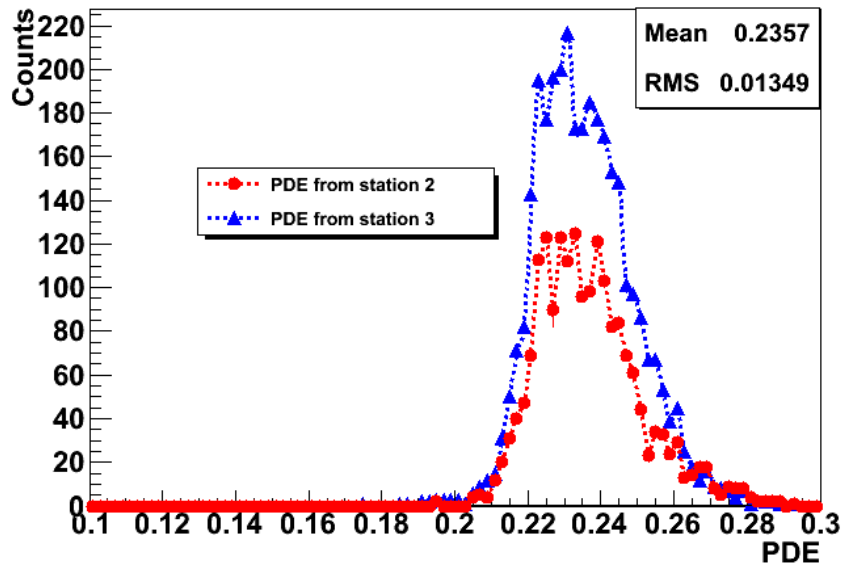
Dispersion



Optical crosstalk temperature dependence



PDE and mean number of photoelectrons validation



$$err = \frac{\langle N \rangle_{or} - \langle N \rangle_{ped}}{\langle N \rangle_{ped}} \times 100$$

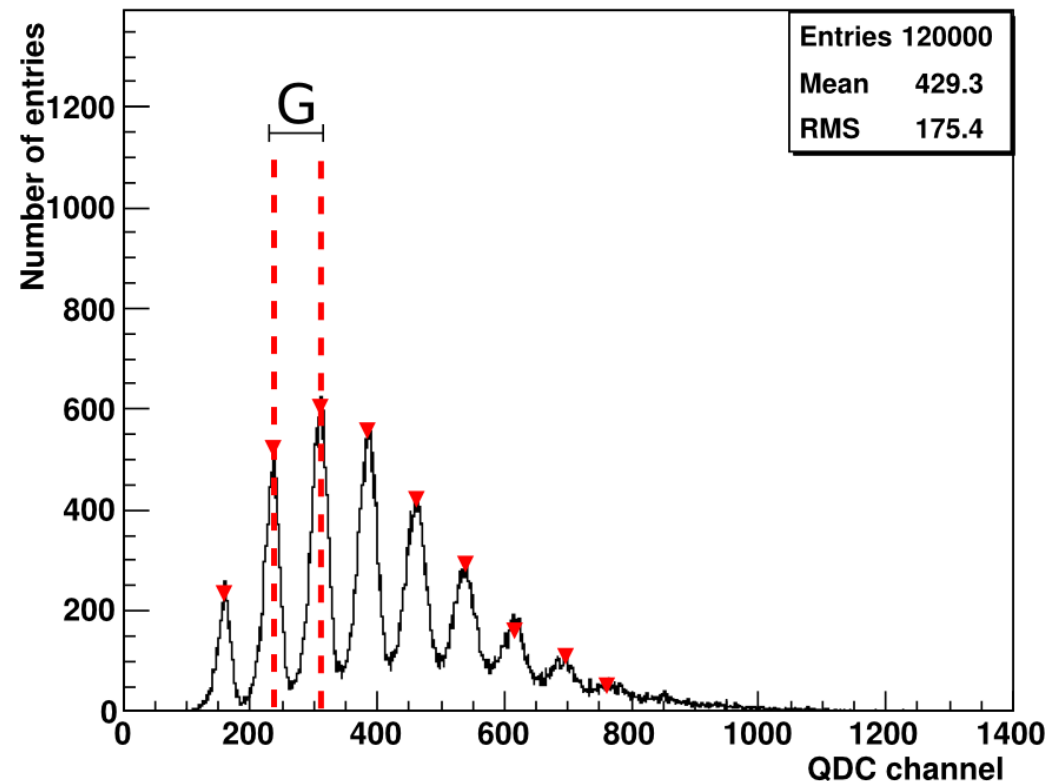
$$\langle N \rangle_{ped} = -\ln(Prob(0))$$

Extracción de la ganancia

- Se identifican los peaks (TSpectrum).
- Se extrae de la diferencia entre dos peaks vecinos

$$N(x) = Gauss(x) + B + Cx$$

$$G_e = \frac{G_{ch} \times QDC_{res}}{e}$$



Readout

